



# BFR540

## NPN 9 GHz wideband transistor

Rev. 6 — 13 September 2011

Product data sheet

## 1. Product profile

### 1.1 General description

The BFR540 is an NPN silicon planar epitaxial transistor in a SOT23 plastic package.

### 1.2 Features and benefits

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability.

### 1.3 Applications

- RF front end wideband applications in the GHz range
  - ◆ Analog and digital cellular telephones
  - ◆ Cordless telephones (CT1, CT2, DECT, etc.)
  - ◆ Radar detectors
  - ◆ Satellite TV tuners (SATV)
  - ◆ MATV/CATV amplifiers
  - ◆ Repeater amplifiers in fiber-optic systems.

### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol    | Parameter                     | Conditions   | Min | Typ | Max | Unit |
|-----------|-------------------------------|--|-----|-----|-----|------|
| $V_{CBO}$ | collector-base voltage        | open emitter   | -   | -   | 20  | V    |
| $V_{CES}$ | collector-emitter voltage     | $R_{BE} = 0 \Omega$  | -   | -   | 15  | V    |
| $I_C$     | collector current (DC)        |  | -   | -   | 120 | mA   |
| $P_{tot}$ | total power dissipation       | $T_{sp} \leq 70 \text{ }^\circ\text{C}$  | [1] | -   | 500 | mW   |
| $h_{FE}$  | DC current gain               | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}$                                      | 100 | 120 | 250 |      |
| $C_{re}$  | feedback capacitance          | $I_C = i_c = 0 \text{ A}; V_{CB} = 8 \text{ V}; f = 1 \text{ MHz}$               | -   | 0.6 | -   | pF   |
| $f_T$     | transition frequency          | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz}$                   | -   | 9   | -   | GHz  |
| $G_{UM}$  | maximum unilateral power gain | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$ |     |     |     |      |
|           |                               | $f = 900 \text{ MHz}$  | -   | 14  | -   | dB   |
|           |                               | $f = 2 \text{ GHz}$  | -   | 7   | -   | dB   |



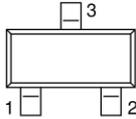
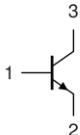
**Table 1. Quick reference data ...continued**

| Symbol       | Parameter            | Conditions  | Min | Typ | Max | Unit |
|--------------|----------------------|---|-----|-----|-----|------|
| $ s_{21} ^2$ | insertion power gain | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$<br>$T_{amb} = 25 \text{ }^\circ\text{C};$<br>$f = 900 \text{ MHz}$ | 12  | 13  | -   | dB   |
| NF           | noise figure         | $\Gamma_s = \Gamma_{opt}; V_{CE} = 8 \text{ V};$<br>$T_{amb} = 25 \text{ }^\circ\text{C}$                       |     |     |     |      |
|              |                      | $I_C = 10 \text{ mA};$<br>$f = 900 \text{ MHz}$   | -   | 1.3 | 1.8 | dB   |
|              |                      | $I_C = 40 \text{ mA};$<br>$f = 900 \text{ MHz}$   | -   | 1.9 | 2.4 | dB   |
|              |                      | $I_C = 10 \text{ mA};$<br>$f = 2 \text{ GHz}$   | -   | 2.1 | -   | dB   |

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 2. Pinning information

**Table 2. Pinning**

| Pin | Description | Simplified outline  | Symbol  |
|-----|-------------|---|---|
| 1   | base        |  |  |
| 2   | emitter     |   |   |
| 3   | collector   |   |   |

*sym021*

## 3. Ordering information

**Table 3. Ordering information**

| Type number | Package |  | Version |
|-------------|---------|--|---------|
|             | Name    | Description                              |         |
| BFR540      | -       | plastic surface mounted package; 3 leads | SOT23   |

## 4. Marking

**Table 4. Marking**

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| BFR540      | 33*                         |

[1] \* = p: Made in Hong Kong  
 \* = t: Made in Malaysia  
 \* = W: Made in China.

## 5. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter                 | Conditions                              | Min | Max  | Unit             |
|-----------|---------------------------|---|-----|------|------------------|
| $V_{CBO}$ | collector-base voltage    | open emitter                            | -   | 20   | V                |
| $V_{CES}$ | collector-emitter voltage | $R_{BE} = 0 \Omega$                     | -   | 15   | V                |
| $V_{EBO}$ | emitter-base voltage      | open collector                          | -   | 2.5  | V                |
| $I_C$     | collector current (DC)    |   | -   | 120  | mA               |
| $P_{tot}$ | total power dissipation   | $T_{sp} \leq 70 \text{ }^\circ\text{C}$ | [1] | 500  | mW               |
| $T_{stg}$ | storage temperature       |   | -65 | +150 | $^\circ\text{C}$ |
| $T_j$     | junction temperature      |   | -   | 175  | $^\circ\text{C}$ |

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

| Symbol         | Parameter   | Conditions | Typ | Unit    |
|----------------|---|------------|-----|---------|
| $R_{th(j-sp)}$ | thermal resistance from junction to soldering point |            | [1] | 260 K/W |

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 7. Characteristics

**Table 7. Characteristics**

$T_j = 25 \text{ }^\circ\text{C}$  unless otherwise specified.

| Symbol       | Parameter                     | Conditions   | Min | Typ | Max | Unit |
|--------------|-------------------------------|--|-----|-----|-----|------|
| $I_{CBO}$    | collector cut-off current     | $I_E = 0 \text{ A}; V_{CB} = 8 \text{ V}$  | -   | -   | 50  | nA   |
| $h_{FE}$     | DC current gain               | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}$  | 100 | 120 | 250 |      |
| $C_e$        | emitter capacitance           | $I_C = i_c = 0 \text{ A}; V_{EB} = 0.5 \text{ V};$<br>$f = 1 \text{ MHz}$                                  | -   | 2   | -   | pF   |
| $C_c$        | collector capacitance         | $I_E = i_e = 0 \text{ A}; V_{CB} = 8 \text{ V};$<br>$f = 1 \text{ MHz}$                                    | -   | 0.9 | -   | pF   |
| $C_{re}$     | feedback capacitance          | $I_C = 0 \text{ A}; V_{CB} = 8 \text{ V};$<br>$f = 1 \text{ MHz}$  | -   | 0.6 | -   | pF   |
| $f_T$        | transition frequency          | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$<br>$f = 1 \text{ GHz}$  | -   | 9   | -   | GHz  |
| $G_{UM}$     | maximum unilateral power gain | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$<br>$T_{amb} = 25 \text{ }^\circ\text{C}$                      | [1] |     |     |      |
|              |                               | $f = 900 \text{ MHz}$  | -   | 14  | -   | dB   |
|              |                               | $f = 2 \text{ GHz}$  | -   | 7   | -   | dB   |
| $ S_{21} ^2$ | insertion power gain          | $I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$<br>$T_{amb} = 25 \text{ }^\circ\text{C}; f = 900 \text{ MHz}$ | 12  | 13  | -   | dB   |

**Table 7. Characteristics ...continued**  
*T<sub>j</sub> = 25 °C unless otherwise specified.*

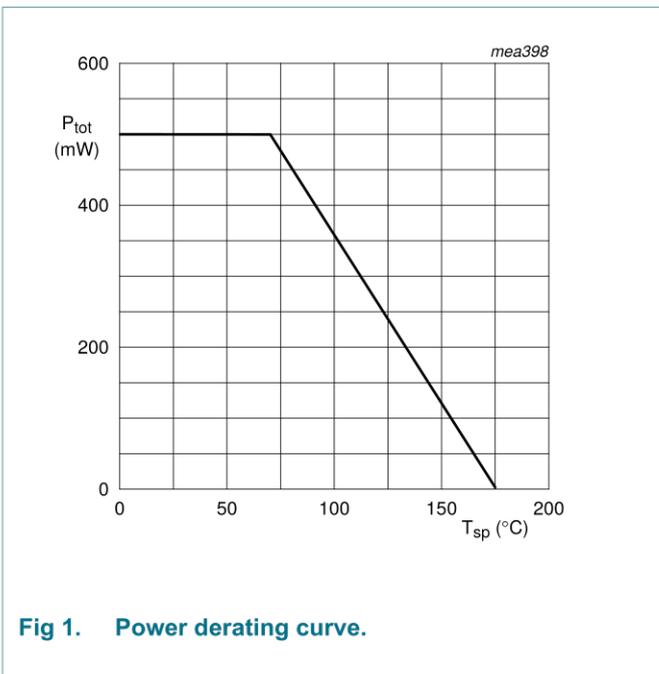
| Symbol              | Parameter                             | Conditions  | Min   | Typ | Max | Unit |
|---------------------|---------------------------------------|---|-------|-----|-----|------|
| NF                  | noise figure                          | $\Gamma_s = \Gamma_{opt}; V_{CE} = 8\text{ V};$<br>$T_{amb} = 25\text{ °C}$                                       |       |     |     |      |
|                     |                                       | $I_C = 10\text{ mA}; f = 900\text{ MHz}$  | -     | 1.3 | 1.8 | dB   |
|                     |                                       | $I_C = 40\text{ mA}; f = 900\text{ MHz}$  | -     | 1.9 | 2.4 | dB   |
|                     |                                       | $I_C = 10\text{ mA}; f = 2\text{ GHz}$  | -     | 2.1 | -   | dB   |
| P <sub>L(1dB)</sub> | output power at 1 dB gain compression | $I_C = 40\text{ mA}; V_{CE} = 8\text{ V};$<br>$R_L = 50\ \Omega; T_{amb} = 25\text{ °C};$<br>$f = 900\text{ MHz}$ | -     | 21  | -   | dBm  |
| I <sub>TO</sub>     | third order intercept point           |   | [2] - | 34  | -   | dBm  |
| V <sub>O</sub>      | output voltage                        | $I_C = 40\text{ mA}; V_{CE} = 8\text{ V};$<br>$Z_L = Z_S = 75\ \Omega;$<br>$T_{amb} = 25\text{ °C}$               | [3] - | 550 | -   | mV   |

[1] G<sub>UM</sub> is the maximum unilateral power gain, assuming s<sub>12</sub> is zero and

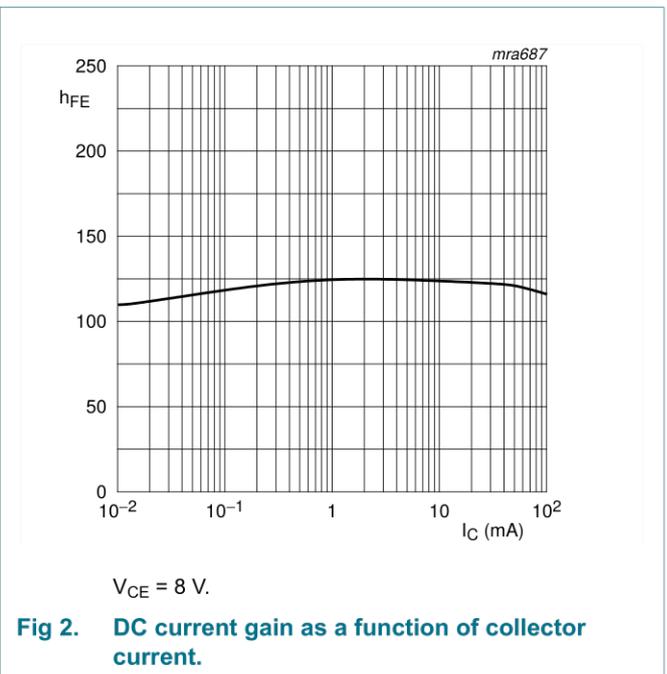
$$G_{UM} = 10 \log \frac{|s_{21}|^2}{(1 - |s_{11}|^2)(1 - |s_{22}|^2)} \text{ dB.}$$

[2] I<sub>C</sub> = 40 mA; V<sub>CE</sub> = 8 V; R<sub>L</sub> = 50 Ω; T<sub>amb</sub> = 25 °C; f = 900 MHz; f<sub>p</sub> = 900 MHz; f<sub>q</sub> = 902 MHz.  
 Measured at f<sub>(2p-q)</sub> = 898 MHz and f<sub>(2q-p)</sub> = 904 MHz.

[3] d<sub>im</sub> = -60 dB (DIN 45004B); V<sub>p</sub> = V<sub>O</sub>; V<sub>q</sub> = V<sub>O</sub> - 6 dB; f<sub>p</sub> = 795.25 MHz; V<sub>R</sub> = V<sub>O</sub> - 6 dB; f<sub>q</sub> = 803.25 MHz;  
 f<sub>r</sub> = 805.25 MHz.  
 Measured at f<sub>(p+q-r)</sub> = 793.25 MHz.

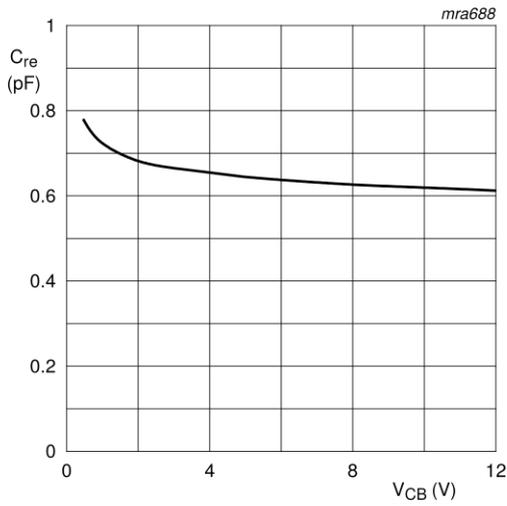


**Fig 1. Power derating curve.**



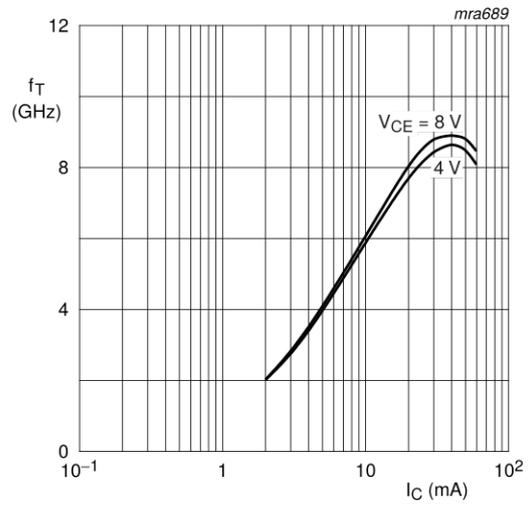
V<sub>CE</sub> = 8 V.

**Fig 2. DC current gain as a function of collector current.**



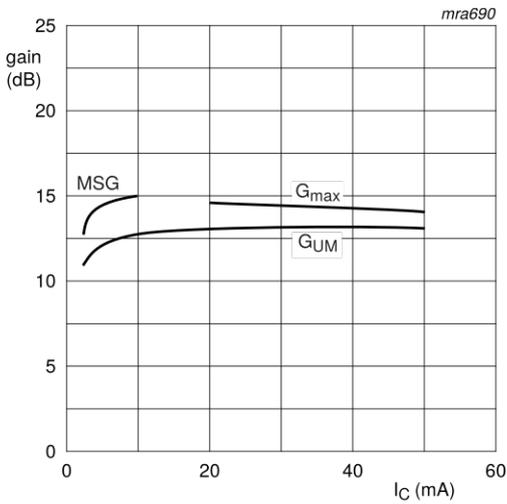
$I_C = 0$  A;  $f = 1$  MHz.

**Fig 3. Feedback capacitance as a function of collector-base voltage.**



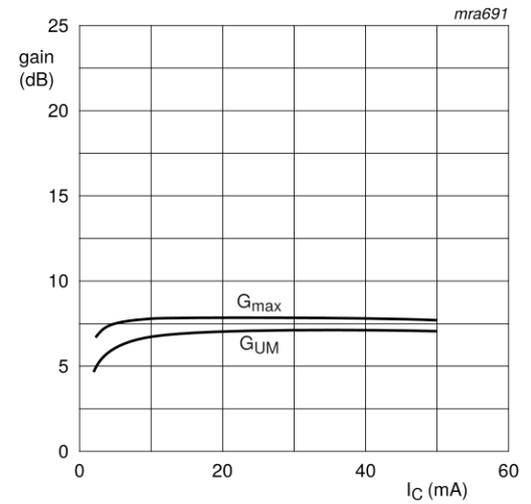
$T_{amb} = 25$  °C;  $f = 1$  GHz.

**Fig 4. Transition frequency as a function of collector current.**



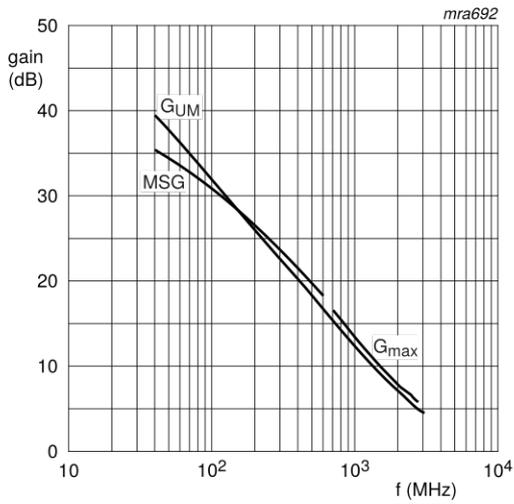
$V_{CE} = 8$  V;  $f = 900$  MHz.

**Fig 5. Gain as a function of collector current.**



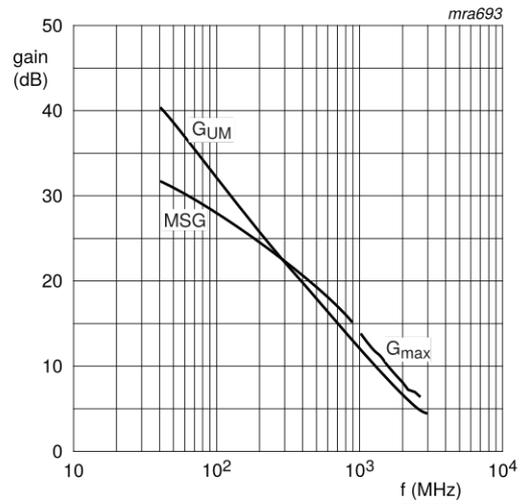
$V_{CE} = 8$  V;  $f = 2$  GHz.

**Fig 6. Gain as a function of collector current.**



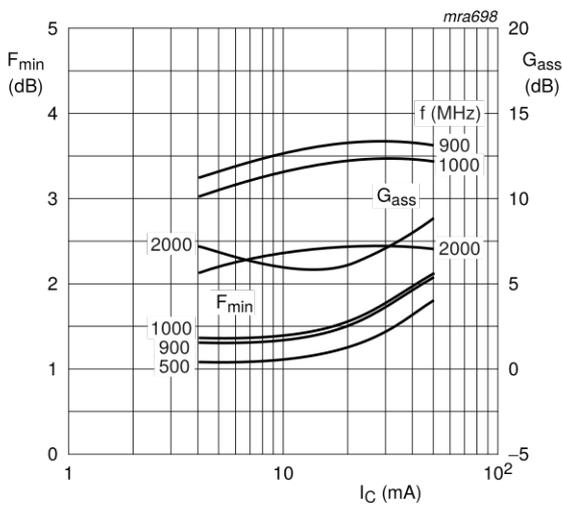
$V_{CE} = 8\text{ V}; I_C = 10\text{ mA}.$

**Fig 7. Gain as a function of frequency;  $I_C = 10\text{ mA}.$**



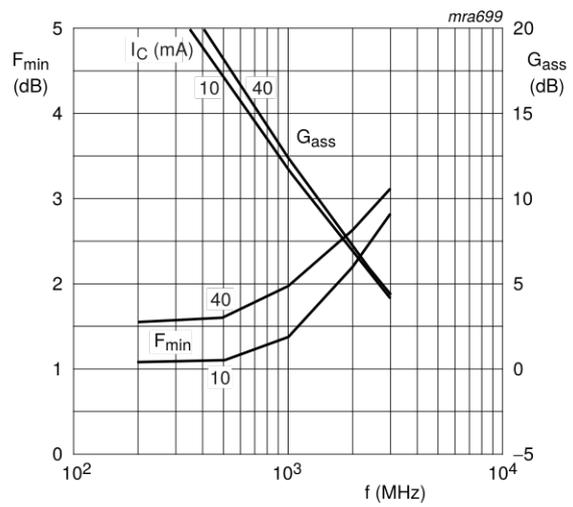
$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}.$

**Fig 8. Gain as a function of frequency;  $I_C = 40\text{ mA}.$**



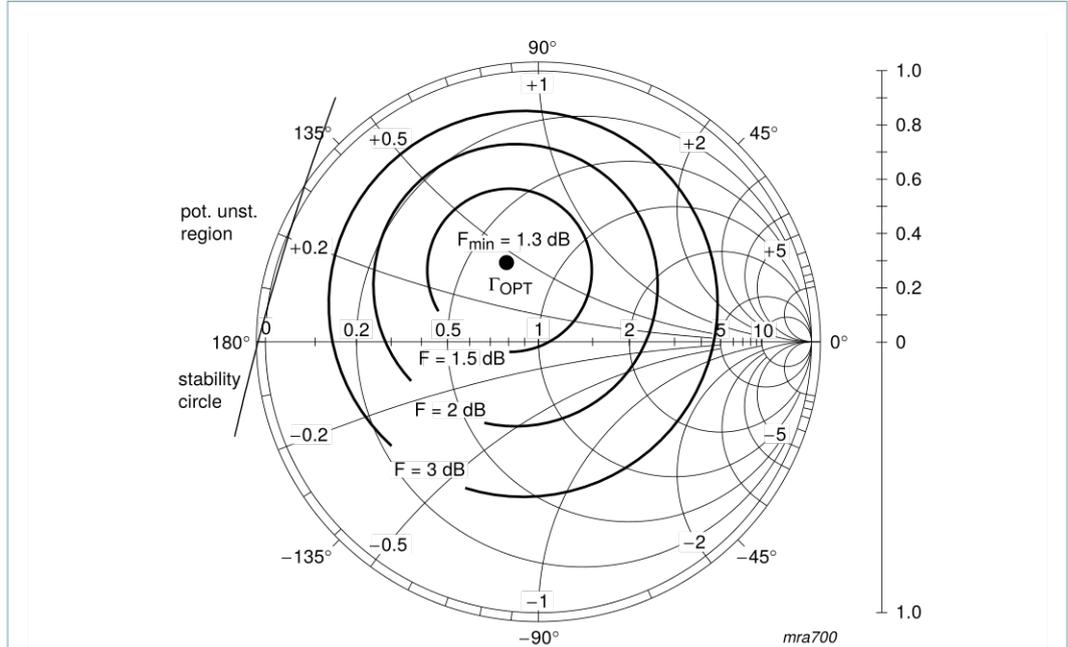
$V_{CE} = 8\text{ V}.$

**Fig 9. Minimum noise figure and associated available gain as a function of collector current.**



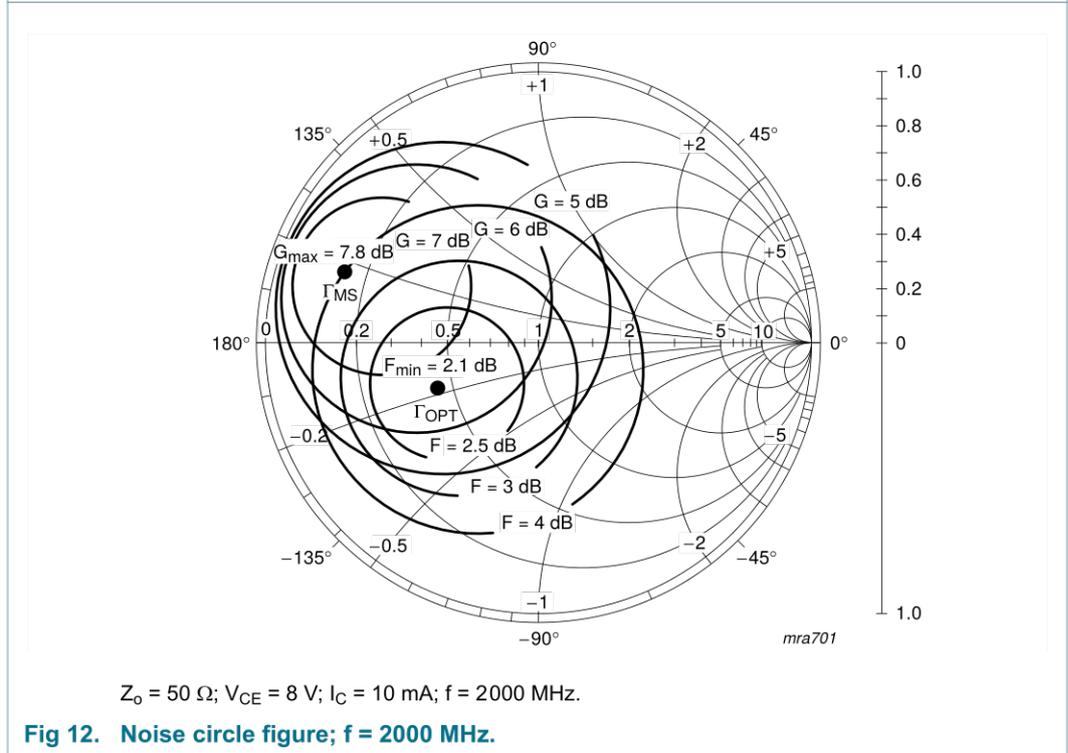
$V_{CE} = 8\text{ V}.$

**Fig 10. Minimum noise figure and associated available gain as a function of frequency.**



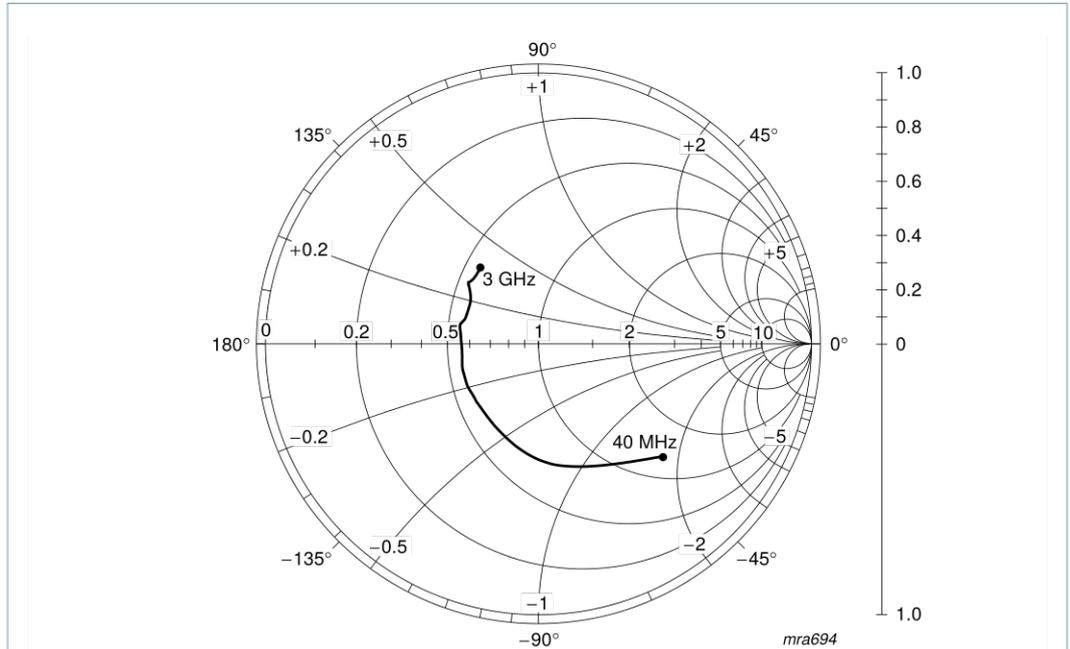
$Z_o = 50 \Omega$ ;  $V_{CE} = 8 \text{ V}$ ;  $I_C = 10 \text{ mA}$ ;  $f = 900 \text{ MHz}$ .

**Fig 11. Noise circle figure;  $f = 900 \text{ MHz}$ .**



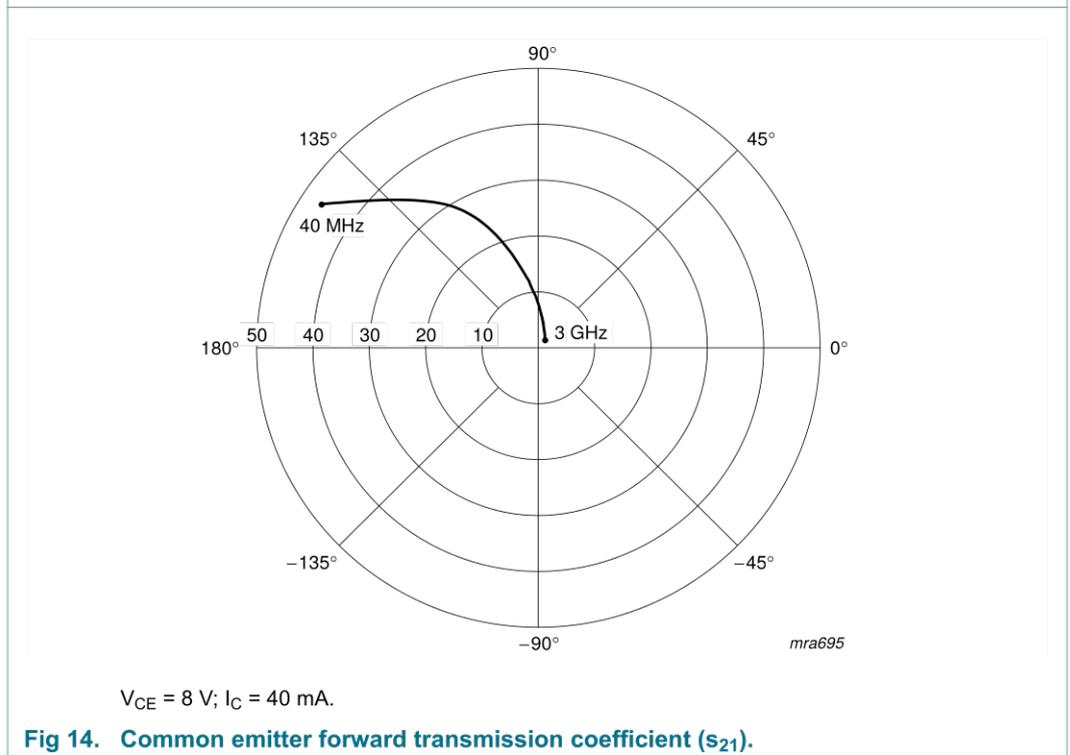
$Z_o = 50 \Omega$ ;  $V_{CE} = 8 \text{ V}$ ;  $I_C = 10 \text{ mA}$ ;  $f = 2000 \text{ MHz}$ .

**Fig 12. Noise circle figure;  $f = 2000 \text{ MHz}$ .**



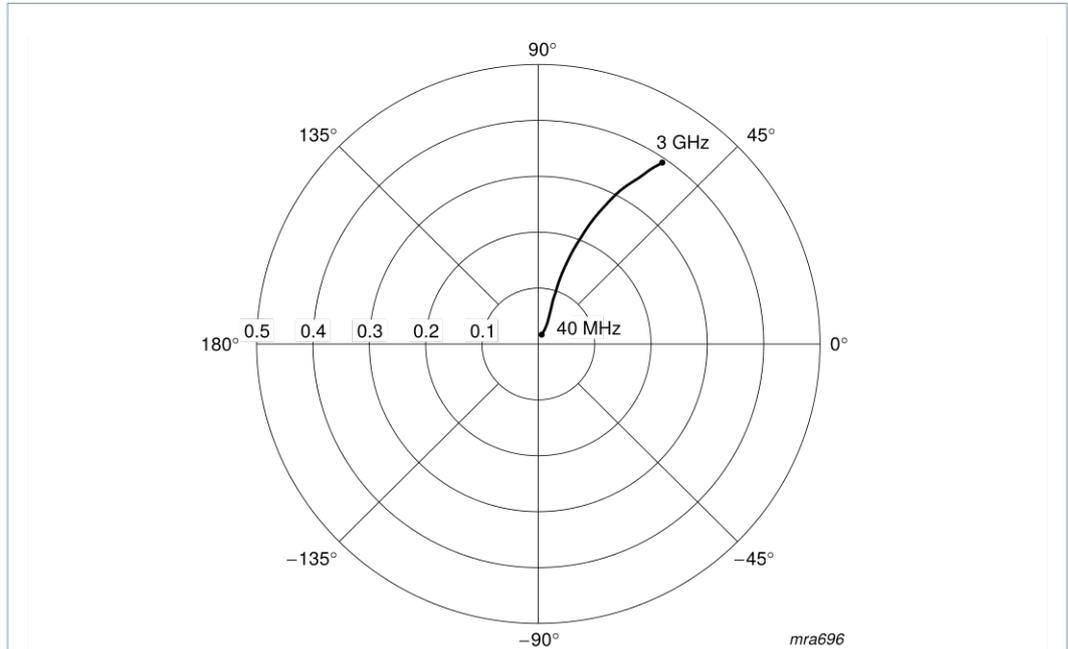
$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}; Z_o = 50\ \Omega.$

**Fig 13. Common emitter input reflection coefficient ( $s_{11}$ ).**



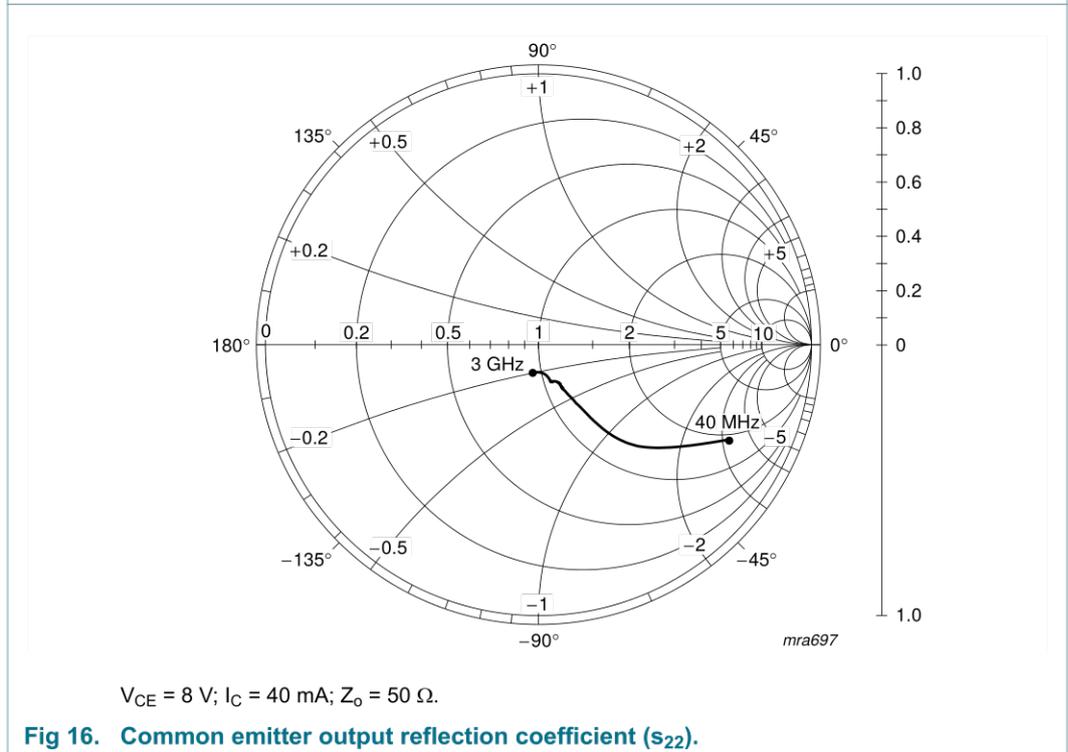
$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}.$

**Fig 14. Common emitter forward transmission coefficient ( $s_{21}$ ).**



$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}$ .

**Fig 15. Common emitter reverse transmission coefficient ( $s_{12}$ ).**



$V_{CE} = 8\text{ V}; I_C = 40\text{ mA}; Z_o = 50\ \Omega$ .

**Fig 16. Common emitter output reflection coefficient ( $s_{22}$ ).**

**8. Package outline**

Plastic surface-mounted package; 3 leads

SOT23

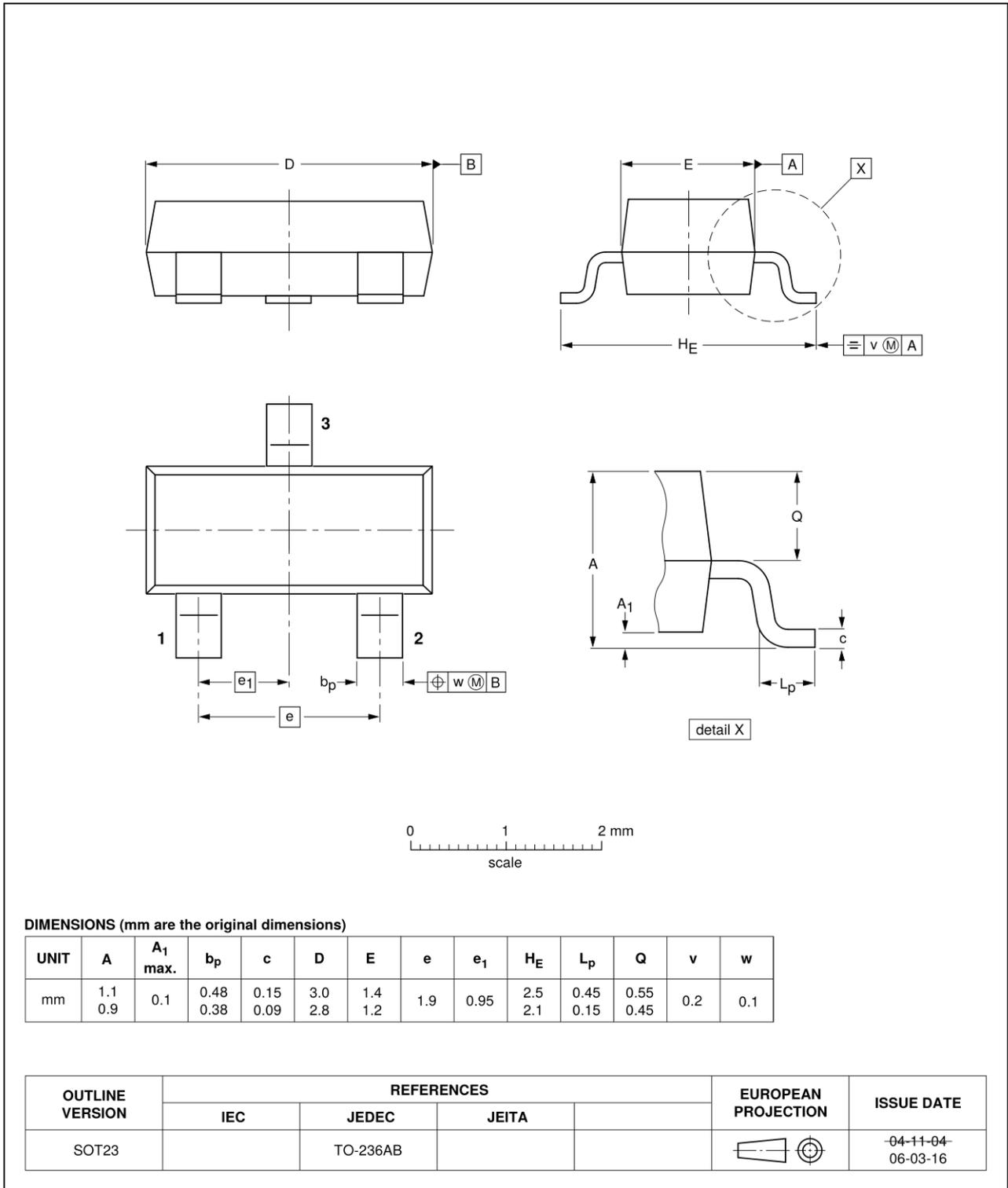


Fig 17. Package outline SOT23 (TO-236AB).

## 9. Revision history

**Table 8. Revision history**

| Document ID                    | Release date | Data sheet status  | Change notice | Supersedes     |
|--------------------------------|--------------|--|---------------|----------------|
| BFR540 v.6                     | 20110913     | Product data sheet   | -             | BFR540 v.5     |
| Modifications:                 |              | <ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Package outline drawings have been updated to the latest version.</li></ul> |               |                |
| BFR540 v.5<br>(9397 750 13398) | 20040901     | Product data sheet   | -             | BFR540 v.4     |
| BFR540 v.4<br>(9397 750 07062) | 20000530     | Product specification  | -             | BFR540 v.3     |
| BFR540 v.3<br>(9397 750 06338) | 19990823     | Product specification  | -             | BFR540_CNV v.2 |
| BFR540_CNV v.2                 | 19971204     | Product specification  | -             | -              |

## 10. Legal information

### 10.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

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